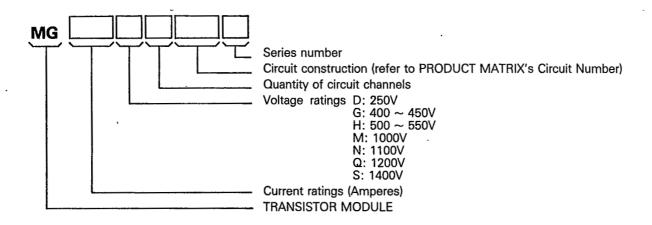
WESTCODE TRANSISTOR MODULES are designed for use in various types of motor control and other high power switching applications and consist of insulated type **DARLINGTON TRANSISTORS.** The electrodes are fully isolated from heat sink. Single ended electrode construction is used to greatly simplify mounting. A wide variety of devices are available with current capability up to 400A and voltage rating up to 1400V.

FEATURES

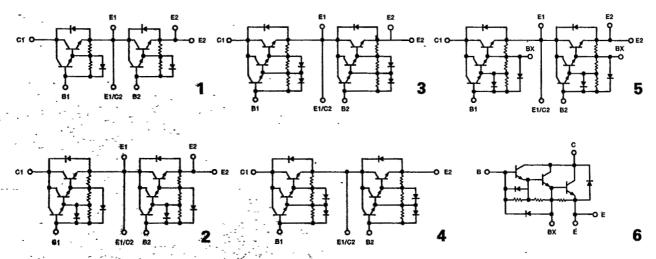
- 1. Electrodes are isolated from the heat sink (2500V AC).
- 2. High DC current Gain ($h_{\rm FE}$) (80 or 100 MIN).
- 3. Low saturation voltage (2 or 2.5V maximum).
- 4. Wide safe operating area.

DESIGNATION CODE

Modules are specified by a type number using the format shown below to indicate the characteristics.



EQUIVALENT CIRCUITS



Туре	Equiv. Circuit	V _{CBO}	V _{CEX} (sus) (V)	V _{CEO (sus)} (V)	V _{EBO} (V)	I _c (DC) (A)	I _{CP} (A) (1msec)	I _F (DC) (A)	I _{FM} (A) (1msec)	1 _B (A)	P _C (W) Tc 25°C	h _{FE min}
MG15N2YK1	2	1100	1100	900	7	15	30	15	30	1,5	150	100
MG25M2YK1	3	1000	1000	880	7	25	50	25	50	1.5	300	100
MG25N2YK1	2	1100	1100	900	7	25	50	25	50	2.5	300	100
MG30G2YL1	1	600	600	450	6	30	60	30	60	10	350	100
MG50G2YL1	1	600	600	450	6	50	100	50	100	5	300	100
MG50M2YK1	. 3	1000	1000	880	7	50	100	50	· 100	5	350	100
MG50N2YK1	3	1100	1100	900	7	50	100	50	100	5	350	100
MG50Q2YK1	3	1200	1200	900	7	50	100	50	100	5	350	100
MG75G2YL1	1	600	600	450	6	75	150	75	150	10	350	80
MG75M2YK1	4	1000	1000	880	7	75	150	75	150	5	400	100
MG75Q2YK1	2	1200	1200	900	7	75	150	75	150	10	400	100
MG100H2YL1	4	600	600	550	7	100	200	100	200	3	400	200
MG100M2YK1	5	1000	1000	880	7	100	200	100	200	10	700	100
MG100Q2YK1	5	1200	1200	900	'7	100	200	100	200	10	700	100
MG150M2YK1	5	1000	1000	880	7	150	300	150	300	15	800	100
MG150Q2YK1	5	1200	1200	900	7	150	300	150	300	20	800	100
MG200M1UK1	6	1000	1000	880	7	200	400	200	400	20	1400	100
MG200Q1UK1	6	1200	1200	900	7	200	400	200	400	20	1400	100
MG300M1UK1	6	1000	1000	880	7	300	600	300	600	30	1600	100
MG300Q1UK1	6	1200	1200	900	7	300	600	300	600	30	1600	100

All Types

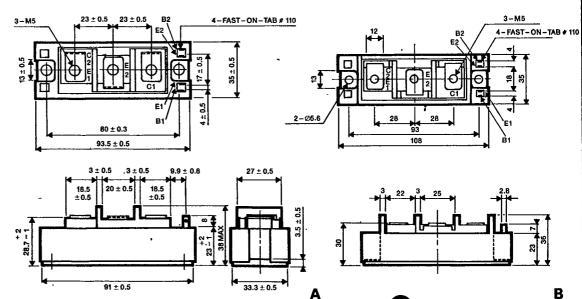
Max. Tj 150°C Storage Temp. Range -40/+125°C Isolation Voltage 2500V

(AC 1 minute)

 $\begin{array}{l} {\rm h_{FE} \ at \ I_c = I_{c(DC)}} \\ {\rm V_{CE} = 5V \ Tj \ 25^{\circ}C} \\ {\rm V_{CE(sat)} \ at \ I_c = I_{c(DC)}} \\ {\rm V_{BE(sat)} \ I_B = 0.02 \ I_c} \\ {\rm Tj = 25^{\circ}C} \end{array}$

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**Screw Torque Terminal M4/M6/Mounting.



G GEP

WESTCODE	SEMICONDUCTORS
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						•		•			
_	V _{CE (sat)} Max (V)	V _{BE (sat)} Max (V)	t _{on} (μS) Max	t _s (μS) Max	t _¢ (μS) Max	V _F (V) Max	t _{rr} (μS) Max	R _{th} (j-s) °C/W max		Outline Drawing	Screw Torque Terminal Mount
iviax (v)	19107 (9)	iviax (v)		IVIBX	KRIAI		IVIAA	Transistor	Diode]	Kg.cm
_	2.5	3.5	2,0	11.0	6.0	1.5	1.0	0.83	1.3	Α	20/30
-	2.5	3.5	2.0	15.0	5.0 .	1.7	1.0	0.41	1.3	A	20/30
_								7,			
_	2.5	3.5	2.0	14.0	6.0	1.7	1.0	0.41	1.3	А	20/30
_	2.0	2,5	1.0	12.0	3.0	1.6	1.0	0,625	1.8	Α	20/30
_	2.0	2.5	1.0	12.0	2.0	1.7	2.0	0.41	1.3	A	20/30
_			1	12.0	2.0		2.0	0.41	,	 	20/50
_	2.5	- 3.5	2.0	15.0	5.0	1.7	1.0	0.35	1.3	Α	20/30
_	2.5	3.5	2.0	15.0	5.0	1.7	1.0	0,35	1.3	A	20/30
_	2.5	3.5	3.0	15,0	5.0	1.8	1.0	0.35	1,3	A	20/30
<u> </u>											
	2.0	2.5	2.0	12.0	2.0	1.7	2.0	0.36	1,3	Α	20/30
_	2.5	3.5	2.0	15.0	5.0	1.8	1.0	0.31	1.3	В	20/30
_	2.5	3.5	3.0	15.0	5.0	1.8	1.0	0.31	1.3	В	20/30
_											
	2.5	3,5	2,0	12.0	3,0	1.8	0.7	0.31	1.3	С	30/30
_	2.5	3.5	2.0	15.0	5.0	1.8	1.0	0.179	0.65	С	30/30
	2.5	3.5	3.0	15.0	5.0	1.8	1.0	0.179	0.65	С	30/30
_	2.5	3.5	2.0	15.0	5.0	1.8	1,0	0.156	0.65	С	30/30
	2.0	3.0	2.0	10.0	0.0	1.0	1,0	0,150	0.05	 	30/30
_	2.5	3.5	3.0	15.0	5.0	1.8	1,0	0.156	0.65	c	30/30
	2.5	3.5	2.0	15.0	5.0	1.8	1.0	0.089	0.325	D	20/30/30**
_		·									
_	2.5	3.5	4.0	15.0	5.0	1.8	1.0	0.089	0.325	D	20/30/30**
_	2.5	3.5	2.0	15.0	5.0	1.8	1.0	0.078	0.325	D	20/30/30**
_	2.5	3.5	4.0	15.0	5.0	1.8	1.0	0,078	0.325	D	20/30/30**
_	i		1			1	1	T	†		1

